

EECS251B : Advanced Digital Circuits and Systems

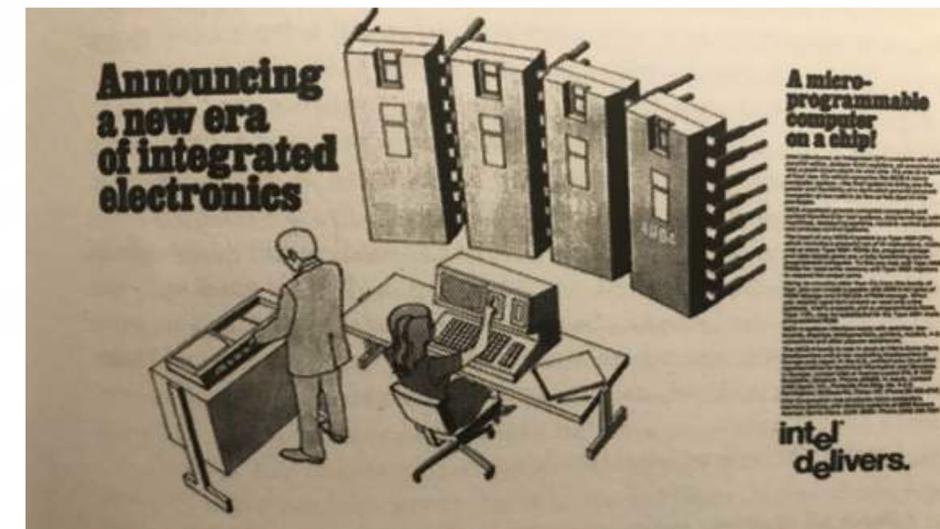
Lecture 20 – Low Power Design

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IEEE MICRO, Nov/Dec 2021

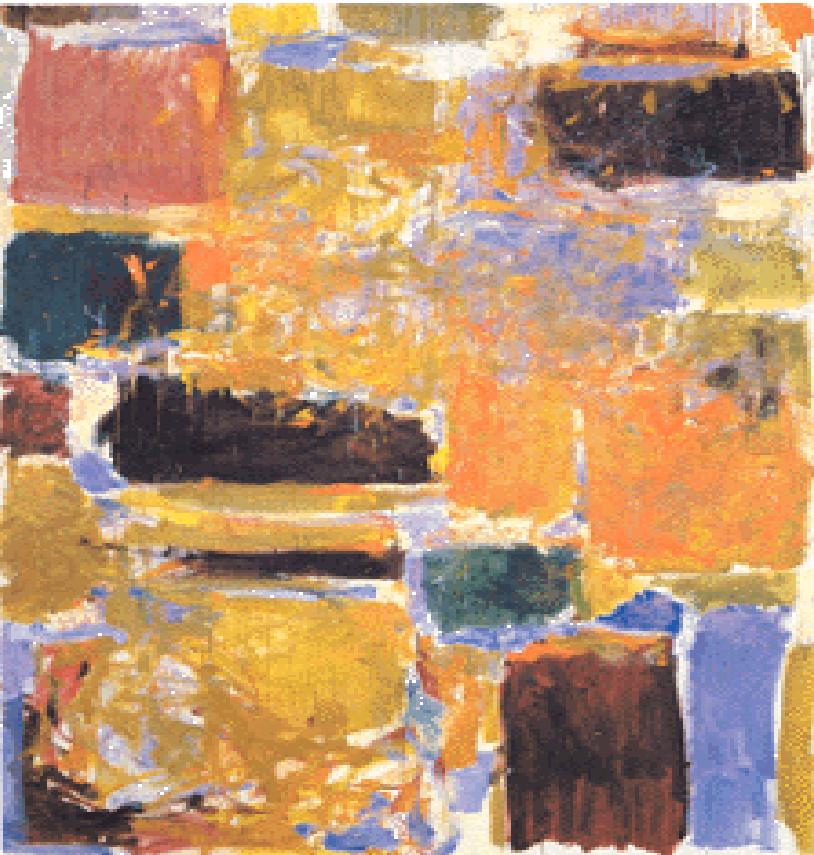
Microprocessor at 50: Looking Back and Looking Forward
Special issue on 50 years of a microprocessor



Advertisement in the Electronics News Weekly in November 1971
announcing the Intel 4004.

Recap

- Power is a primary design constraint
 - In both cloud and edge systems
- Excess performance traded off for power savings



Architectural Optimizations

Optimal Processors

- Processors used to be optimized for performance
 - Optimal logic depth was found to be 8-11 FO4 delays in superscalar processors
 - 1.8-3 FO4 in sequentials, rest in combinatorial
 - Kunkel, Smith, ISCA'86
 - Hriskesh, Jouppi, Farkas, Burger, Keckler, Shivakumar, ISCA'02
 - Harstein, Puzak, ISCA'02
 - Sprangle, Carmean, ISCA'02
- But those designs have very high power dissipation
 - Need to optimize for both performance and power/energy

From System View: What is the Optimum?

- How do sensitivities relate to more traditional metrics:
 - Power per operation (MIPS/W, GOPS/W, TOPS/W)
 - Energy per operation (Joules per op)
 - Energy-delay product
- Can be reformatted as a goal of optimizing power \times delayⁿ
 - n = 0 – minimize power per operation
 - n = 1 – minimize energy per operation
 - n = 2 – minimize energy-delay product
 - n = 3 – minimize energy-(delay)² product

Optimization Problem

- Set up optimization problem:
 - Maximize performance under energy constraints
 - Minimize energy under performance constraints
- Or minimize a composite function of $E^n D^m$
 - What are the right n and m?
 - $n = 1, m = 1$ is EDP – improves at lower V_{DD}
 - $n = 1, m = 2$ is invariant to V_{DD}
 - $E \sim CV_{DD}^2$
 - $D \sim 1/V_{DD}$

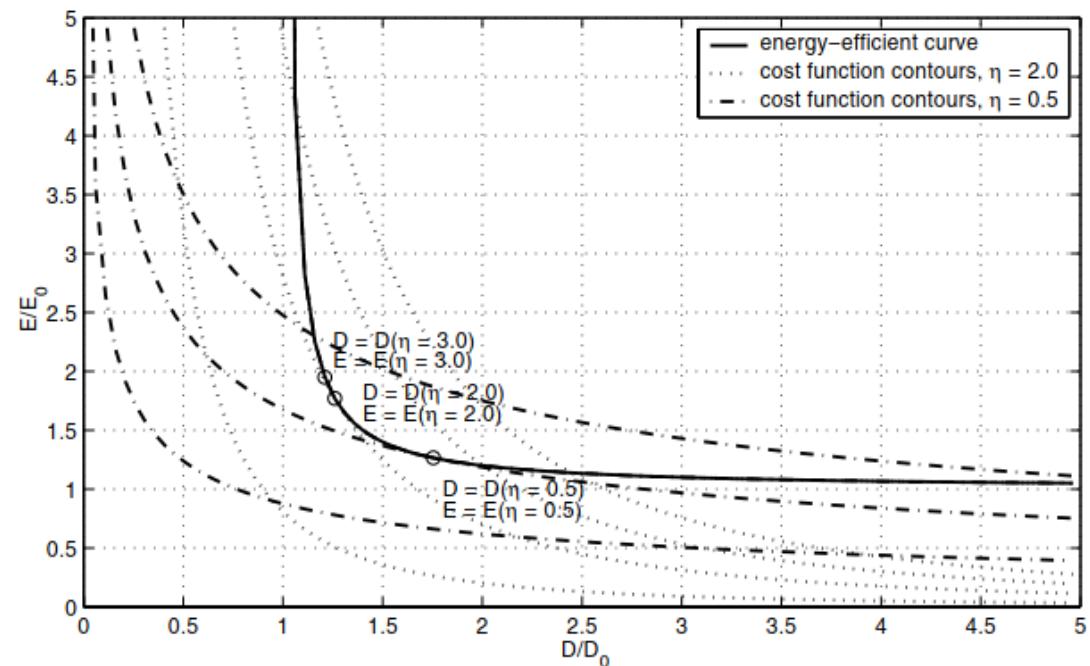
Hardware Intensity

- Introduced by Zyuban and Strenski in 2002.
- Measures where is the design on the Energy-Delay curve
- Parameter in cost function optimization

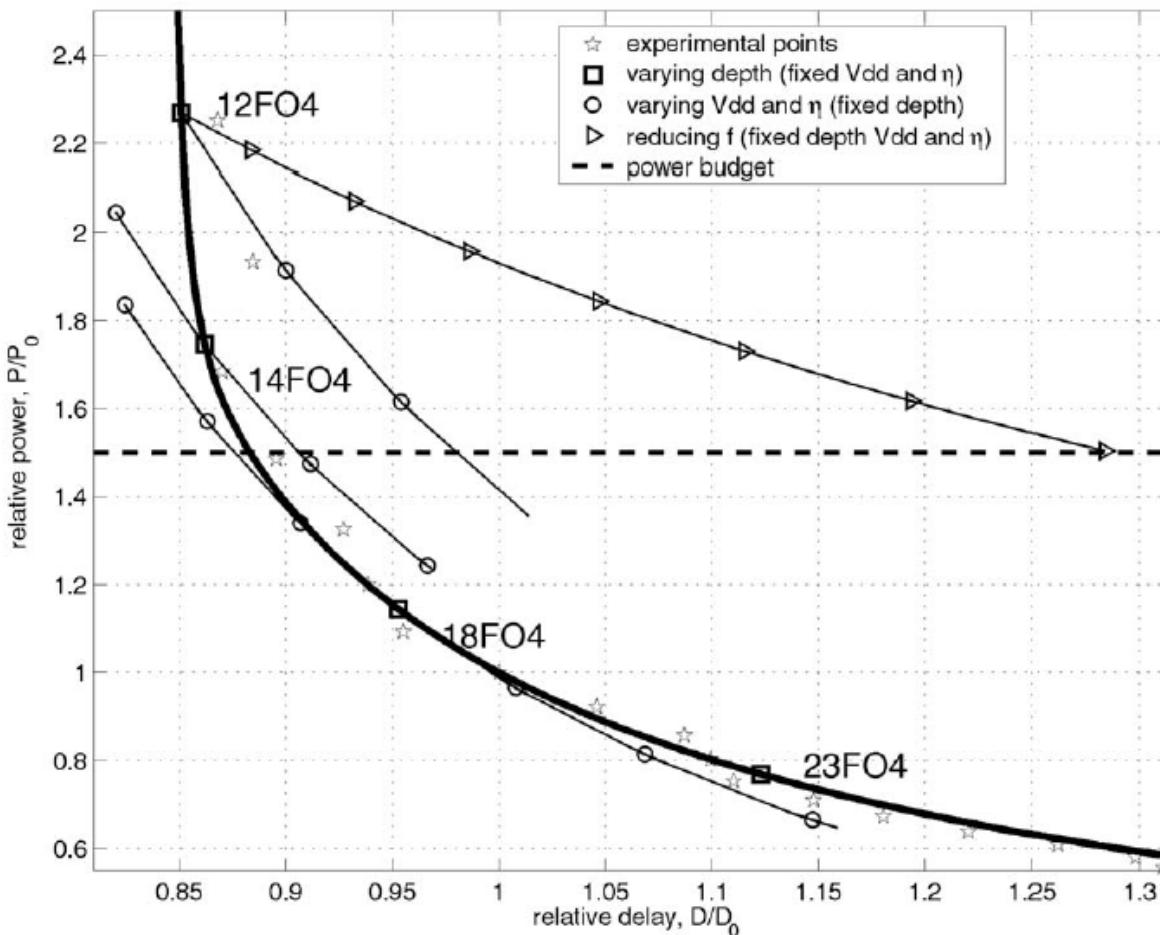
$$F_c = (E/E_0)(D/D_0)^\eta \quad 0 \leq \eta < +\infty,$$

$$\eta = - \left. \frac{D \partial E}{E \partial D} \right|_v$$

Slope of the optimal E-D curve at the chosen design point



Optimum Across Hierarchy Layers

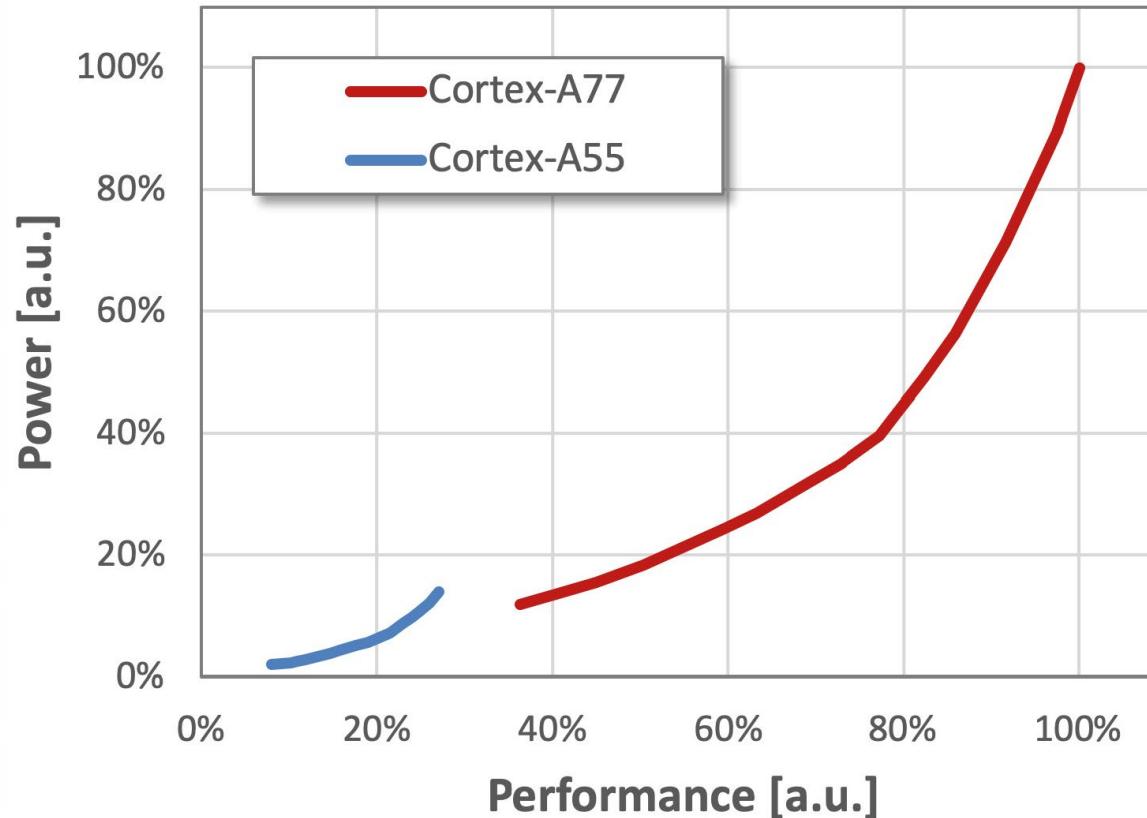


Zyuban et al, TComp'04

Optimal logic depth in pipelined processors is $\sim 18\text{FO}_4$
Relatively flat in the 16-22FO4 range

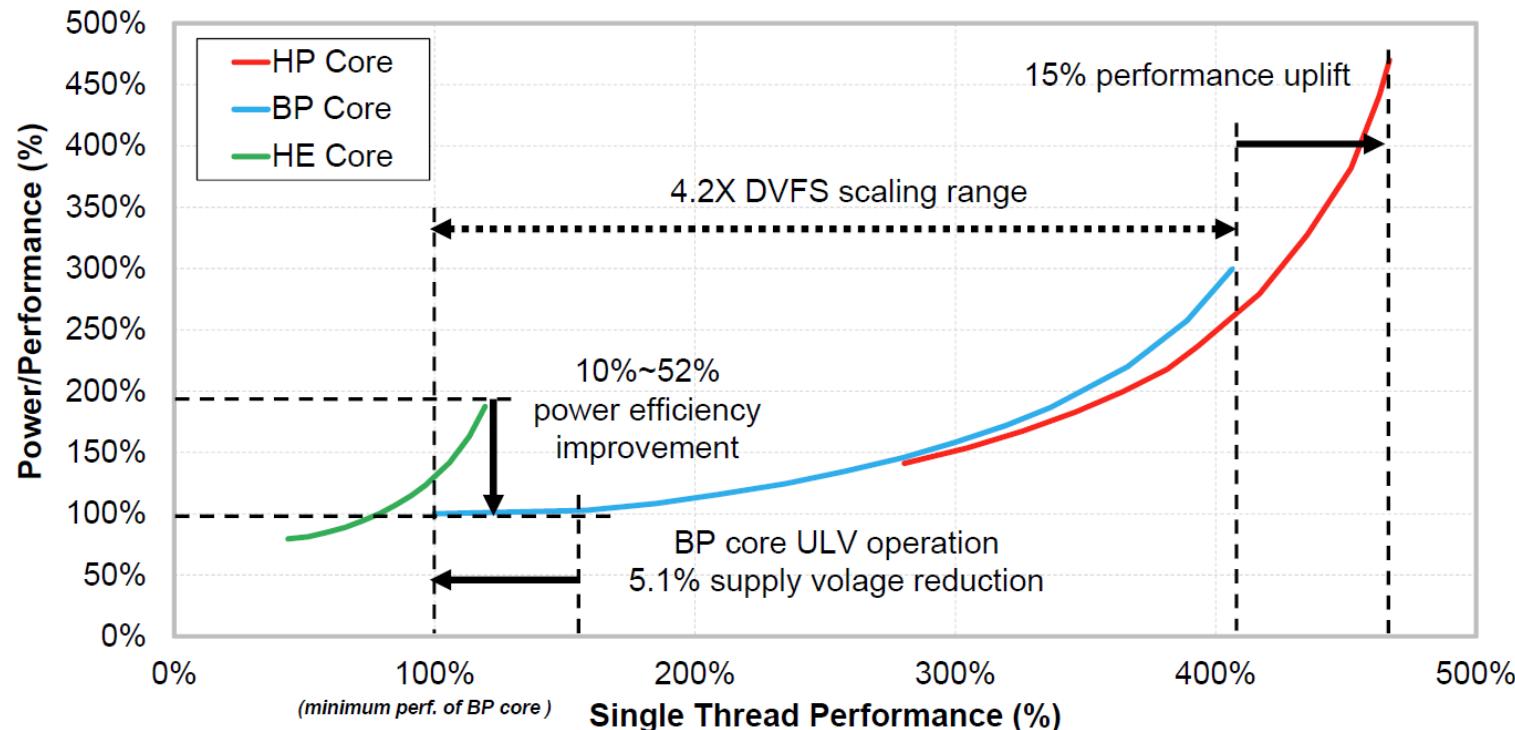
Architectural Tradeoffs

- H, Mair, ISSCC'20



Architectural Tradeoffs: Tri-Gear

- HP: High performance (ARM Cortex A78, optimized for speed, 3.0GHz)
- BP: Balanced performance (ARM Cortex A78, optimized for power, 2.6GHz))
- HE: High efficiency (ARM A55, 2.0GHz)



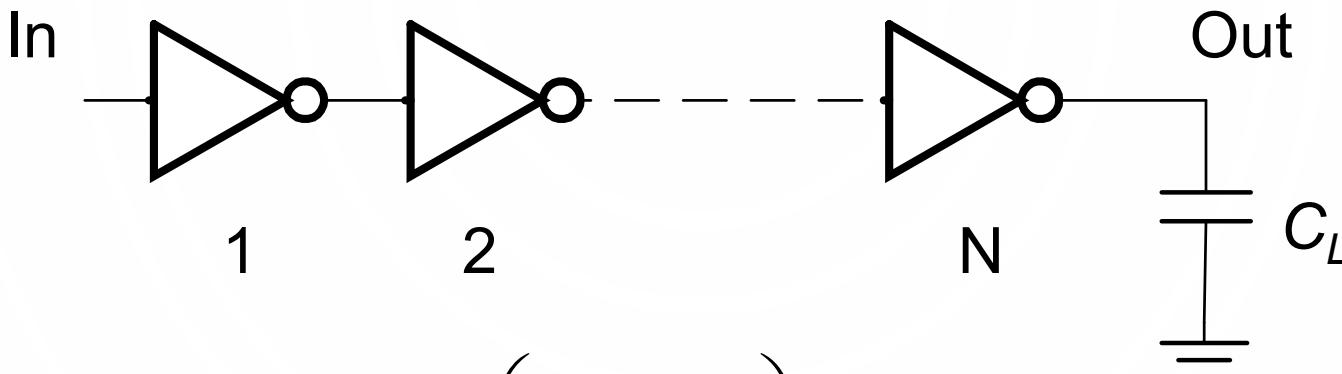
Announcements

- Quiz 2 today
- Homework 3 due next week



Circuit-Level Tradeoffs

Alpha-Power Based Delay Model



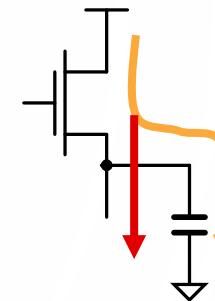
$$t_{pi} = \frac{K_d V_{DD}}{(V_{DD} - V_{Th})^\alpha} \left(1 + \frac{C_{L,i}}{C_{in,i}} \right)$$

$$D = \sum t_{pi} = \sum \frac{K_d V_{DD}}{(V_{DD} - V_{Th})^\alpha} \left(1 + \frac{W_{L,i}}{W_{in,i}} \right)$$

Energy Models

◆ Switching

$$E_{Sw} = \alpha_{0 \rightarrow 1} (C_{L,i} + C_{int,i}) V_{DD}^2$$



◆ Leakage

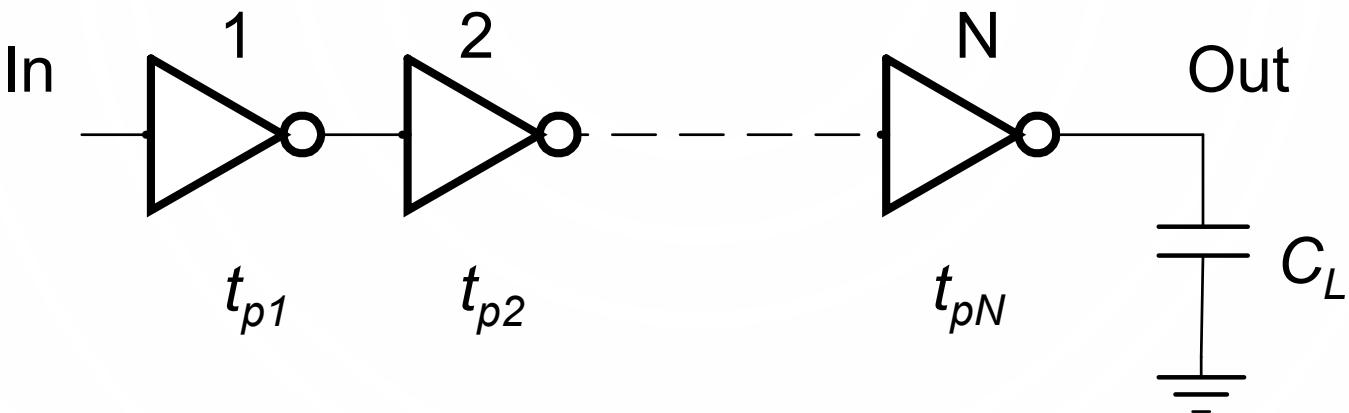
$$E_{Lk} = W_{ln} I_0 e^{-\frac{(V_{Th} - \gamma V_{DD})}{nV_t}} V_{DD} D$$

Sizing, Supply, Threshold Optimization

- Transistor sizing can yield large power savings with small delay penalties
 - Gate sizing
 - Beta-ratio adjustments
 - (Stack resizing)
- Supply voltage affects both active and leakage energy
- Threshold voltage affects primarily the leakage

$$\beta = W_p/W_n$$

Apply to Sizing of an Inverter Chain



Unconstrained energy: find min $D = \sum t_{pi}$

$$C_{gin,j} = \sqrt{C_{gin,j-1} C_{gin,j+1}}$$

$$W_j = \sqrt{W_{j-1} W_{j+1}}$$

Constrained energy: find min D , under $E < E_{max}$

Where $E = \sum e_i$

Constrained Optimization

- Find $\min(D)$ subject to $E = E_{max}$
 - *Constrained function minimization*
- E.g. Lagrange multipliers

Or dual:

$$\Lambda(x) = D(x) + \lambda(E(x) - E_{max})$$

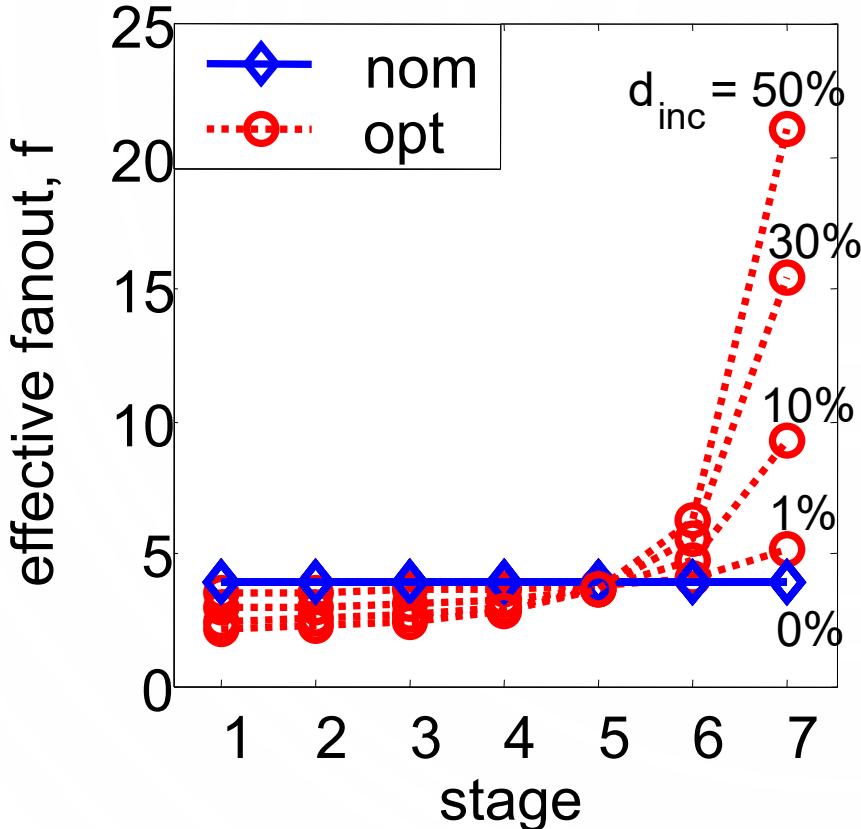
$$K(x) = E(x) + \lambda(D - D_{max})$$

$$\frac{\partial \Lambda}{\partial x} = 0$$

- Can solve analytically for $x = W_i, V_{DD}, V_{Th}$

Inverter Chain: Sizing Optimization

Inverter Chain: Sizing Optimization



$$W_j = \sqrt{\frac{W_{j-1}W_{j+1}}{1 + \lambda W_{j-1}}}$$

[Ma, Franzon, *IEEE JSSC*, 9/94]

$$\lambda = -\frac{2KV_{DD}^2}{\tau_{nom}S_W}$$

$$S_W \propto \frac{e_j}{f_j - f_{j-1}}$$

e_i – energy per stage
 f_i – fanout per stage

Stojanovic, ICCAD'02

- **Variable taper achieves minimum energy**
- **Reduce number of stages at large d_{inc}**

Sensitivity to Sizing and Supply

- Gate sizing (W_i)

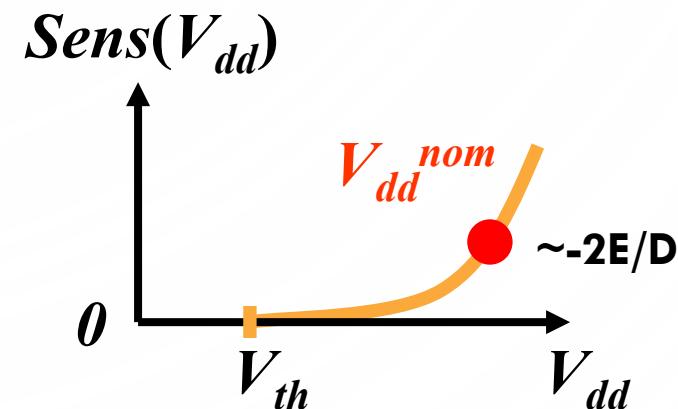
$$-\frac{\partial E_{sw}}{\partial D} \Bigg/ \frac{\partial W_j}{\partial D} = \frac{e_j}{\tau_{nom} (f_j - f_{j-1})}$$

∞ for equal f_{eff}
(D_{min})

- Supply voltage (V_{dd})

$$-\frac{\partial E_{sw}}{\partial D} \Bigg/ \frac{\partial V_{DD}}{\partial D} = \frac{E_{sw}}{D} 2 \frac{1 - x_v}{\alpha - 1 + x_v}$$

$$x_v = (V_{Th} + \Delta V_{Th}) / V_{dd}$$

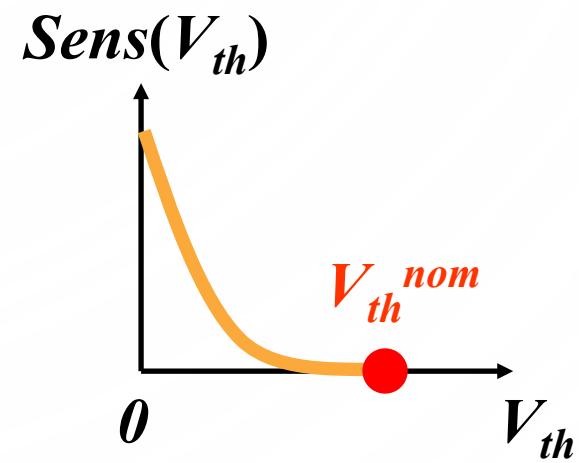


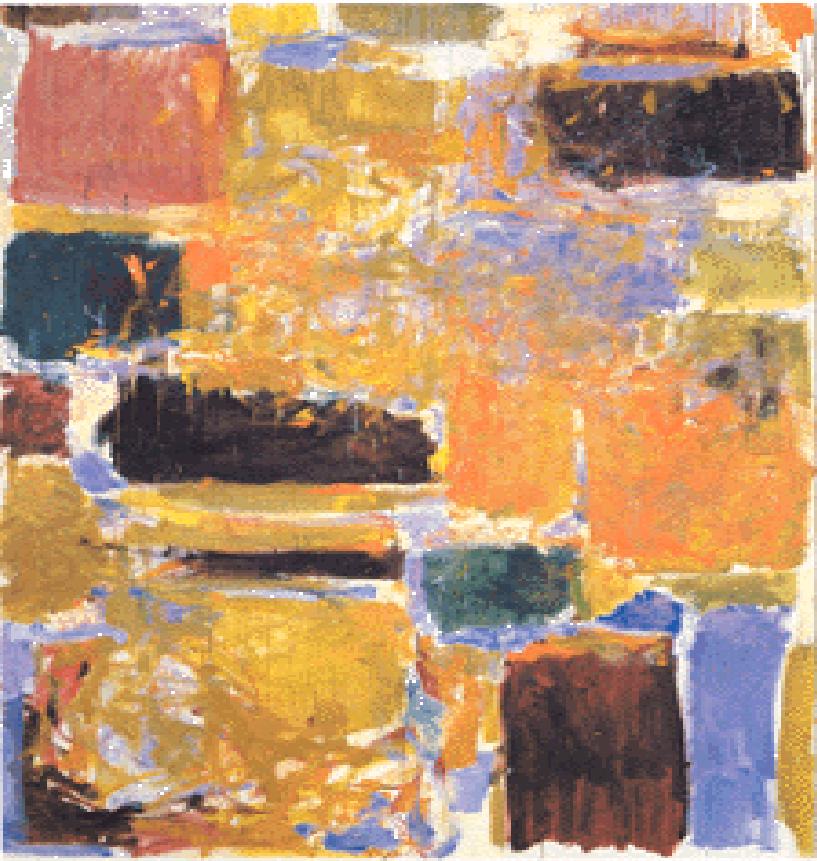
Sensitivity to V_{th}

- Threshold voltage (V_{th})

$$-\frac{\partial E}{\partial \Delta V_{th}} = P_{Lk} \left(\frac{V_{DD} - V_{Th} - \Delta V_{Th}}{\alpha n V_t} - 1 \right)$$

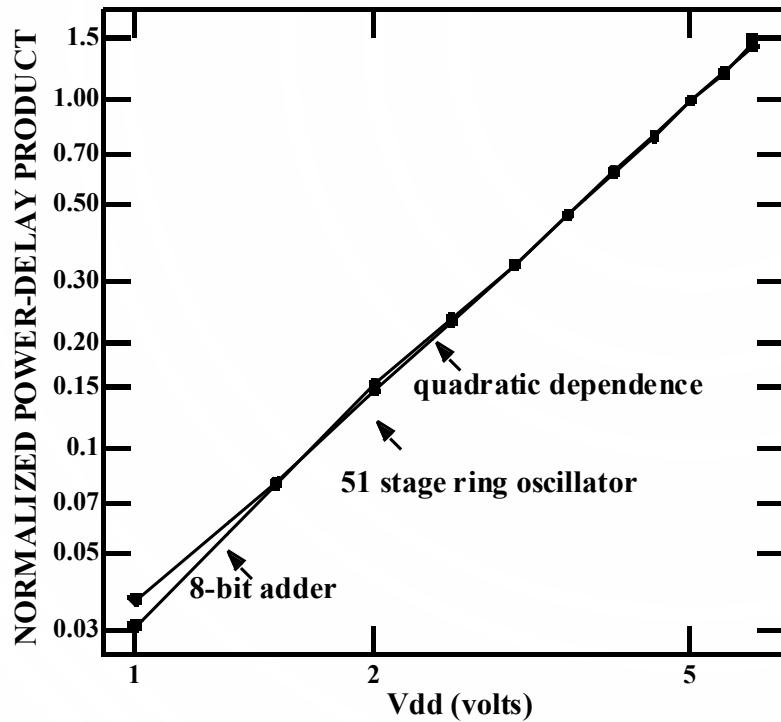
Low initial leakage
⇒ speedup comes for “free”





Scaling Supplies

Reducing V_{dd}



$$P \times t_d = E_t = C_L * V_{dd}^2$$

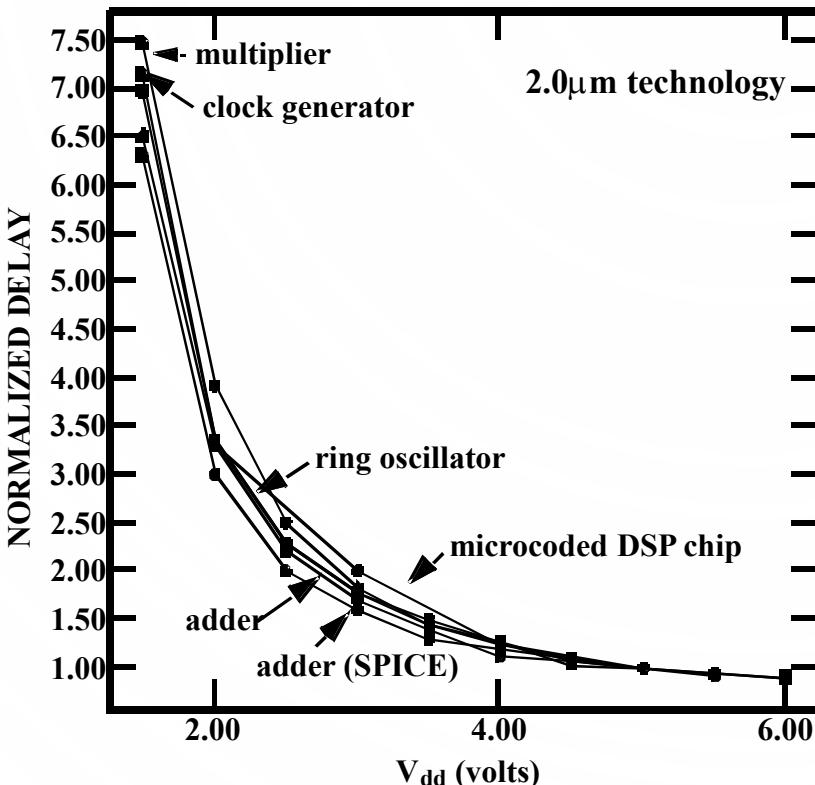
$$\frac{E(V_{dd}=2)}{E(V_{dd}=5)} = \frac{(C_L) * (2)^2}{(C_L) * (5)^2}$$

$$E(V_{dd}=2) \approx 0.16 E(V_{dd}=5)$$

- Strong function of voltage (V^2 dependence).
- Relatively independent of logic function and style.
- Power Delay Product Improves with lowering V_{DD} .

Chandrakasan, JSSC'92

Lower V_{DD} Increases Delay



$$T_d = \frac{C_L * V_{dd}}{I}$$

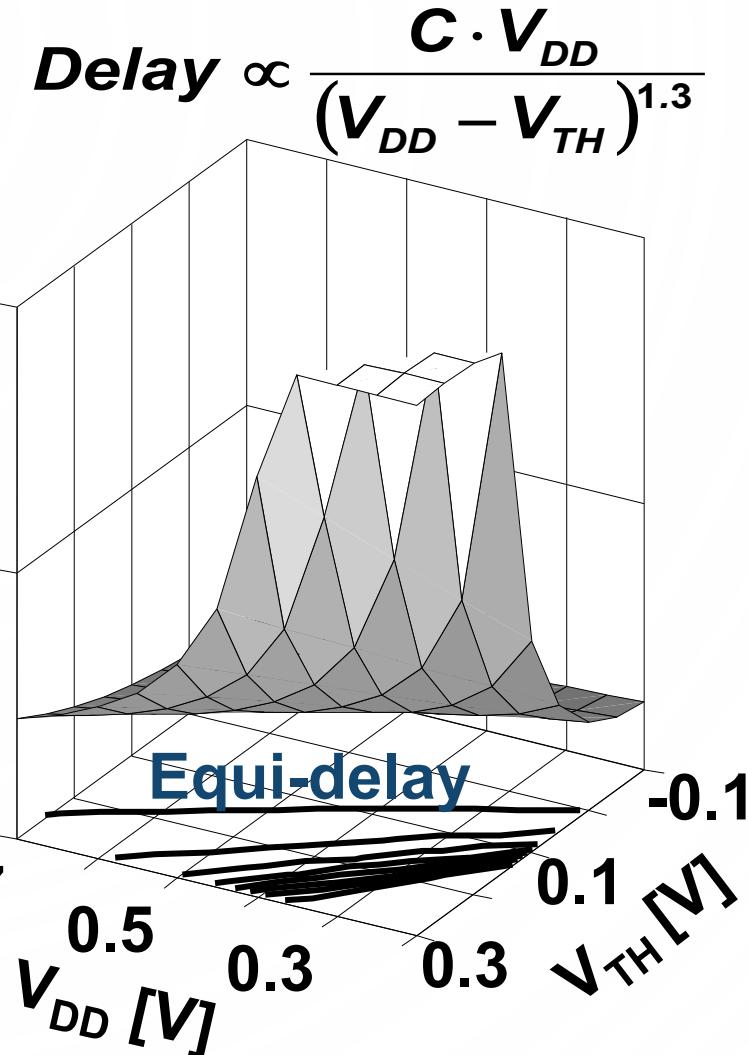
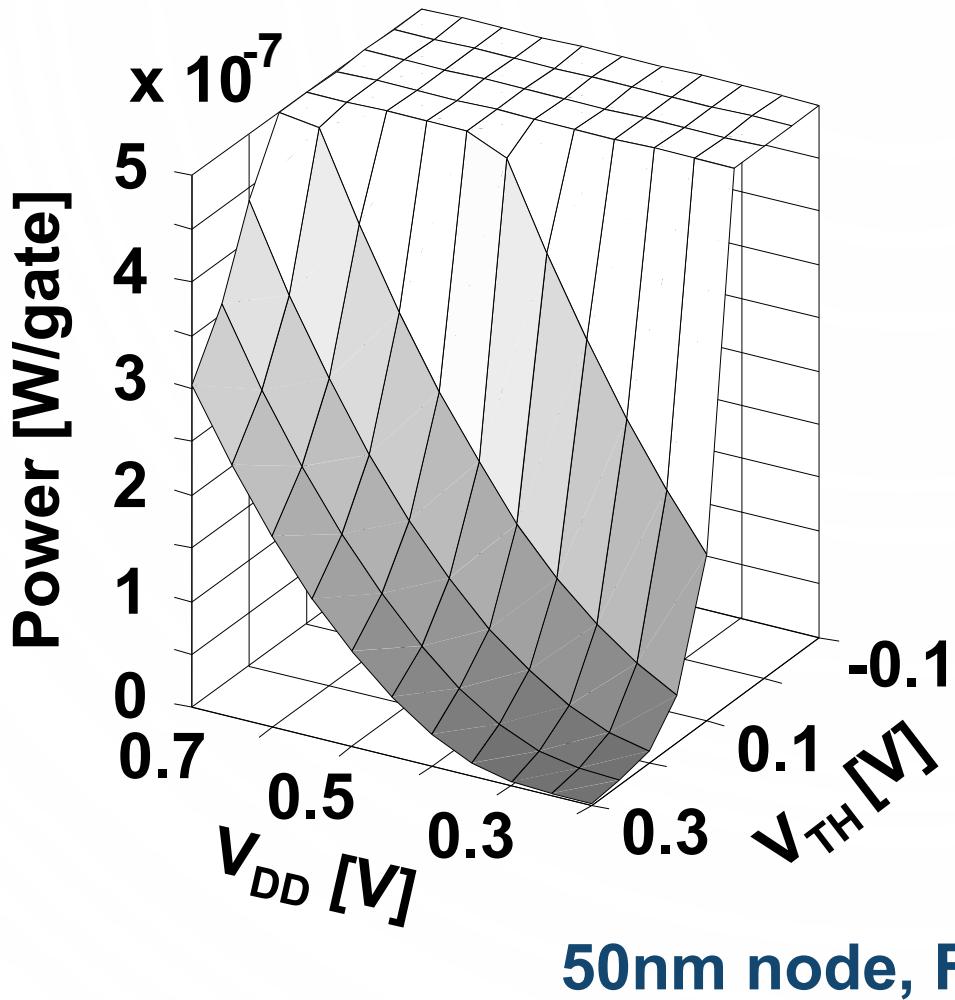
$$I \sim (V_{dd} - V_t)^2$$

$$\frac{T_d(V_{dd}=2)}{T_d(V_{dd}=5)} = \frac{(2) * (5 - 0.7)^2}{(5) * (2 - 0.7)^2} \approx 4$$

- Relatively independent of logic function and style.

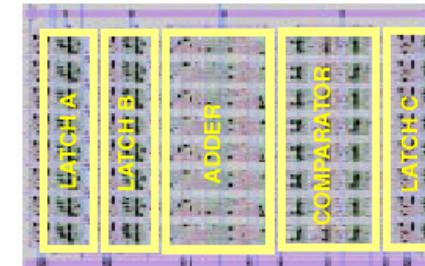
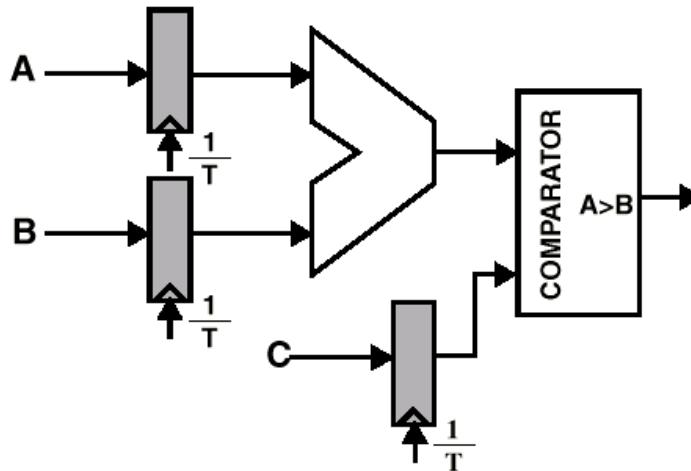
Trade-off Between Power and Delay

$$\text{Power} = a \cdot f \cdot C \cdot V_{DD}^2 + I_0 \cdot 10^{-\frac{V_{TH}}{s}} \cdot V_{DD}$$



Architecture Trade-off for Fixed-rate Processing

Reference Datapath

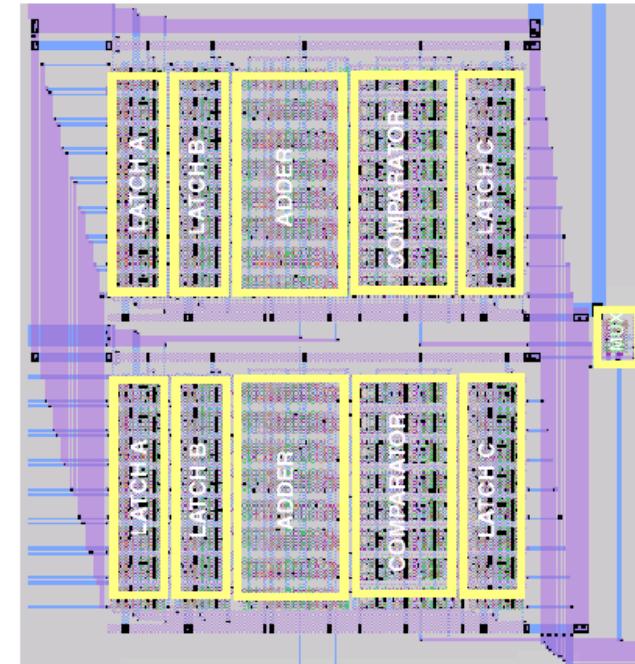
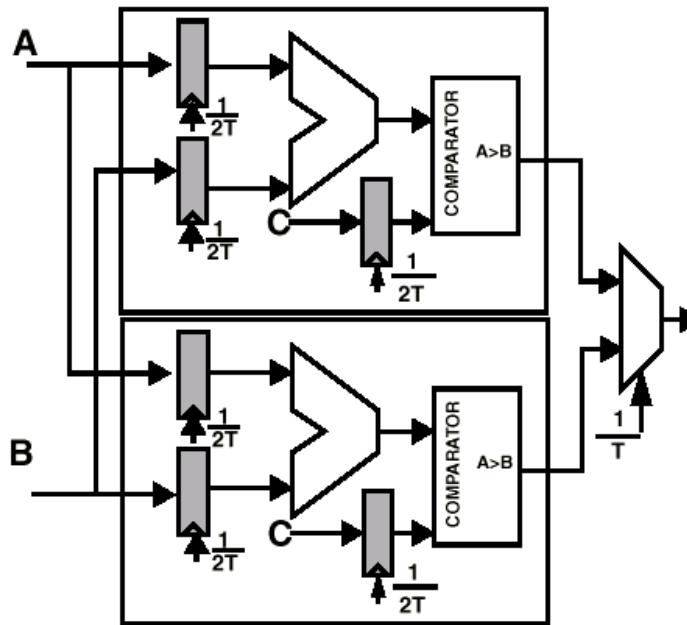


Area = $636 \times 833 \mu\text{m}^2$

- Critical path delay $\Rightarrow T_{\text{adder}} + T_{\text{comparator}} (= 25\text{ns})$
 $\Rightarrow f_{\text{ref}} = 40\text{Mhz}$
- Total capacitance being switched = C_{ref}
- $V_{\text{dd}} = V_{\text{ref}} = 5\text{V}$
- Power for reference datapath = $P_{\text{ref}} = C_{\text{ref}} V_{\text{ref}}^2 f_{\text{ref}}$

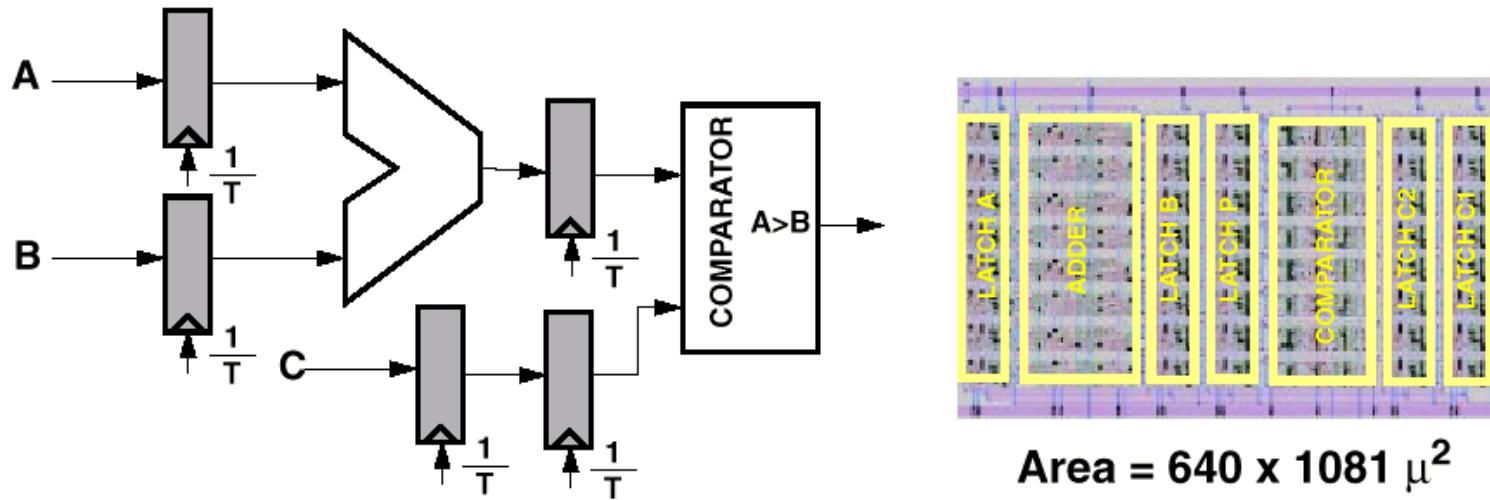
from [Chandrakasan92] (IEEE JSSC)

Parallel Datapath



- The clock rate can be reduced by half with the same throughput $\Rightarrow f_{\text{par}} = f_{\text{ref}} / 2$
- $V_{\text{par}} = V_{\text{ref}} / 1.7$, $C_{\text{par}} = 2.15C_{\text{ref}}$
- $P_{\text{par}} = (2.15C_{\text{ref}}) (V_{\text{ref}}/1.7)^2 (f_{\text{ref}}/2) \approx 0.36 P_{\text{ref}}$

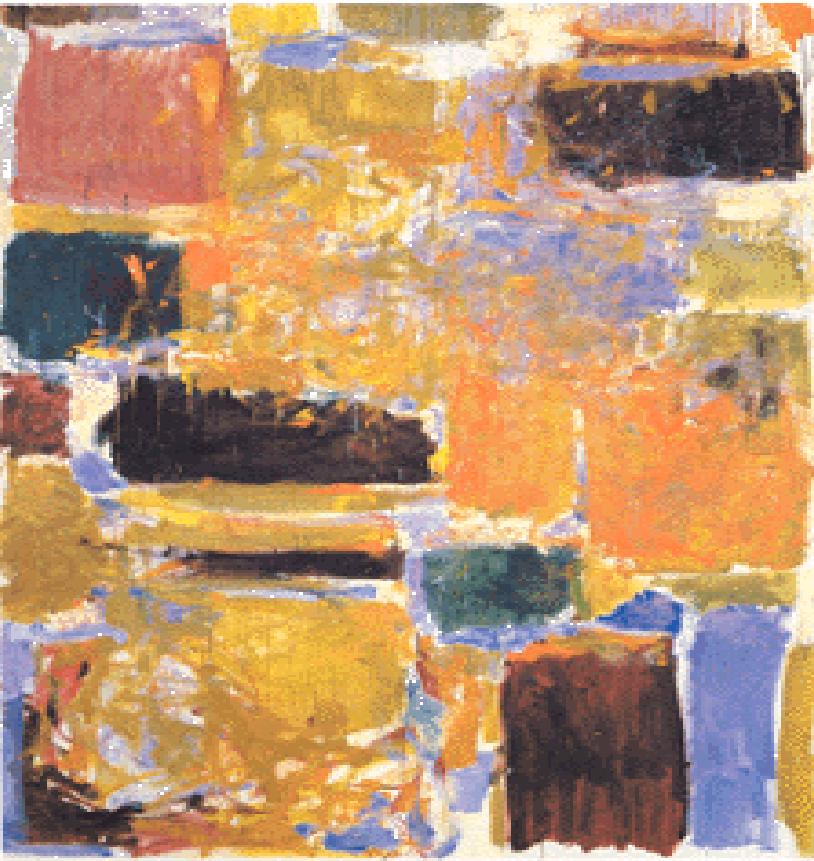
Pipelined Datapath



- Critical path delay is less $\Rightarrow \max [T_{\text{adder}}, T_{\text{comparator}}]$
- Keeping clock rate constant: $f_{\text{pipe}} = f_{\text{ref}}$
Voltage can be dropped $\Rightarrow V_{\text{pipe}} = V_{\text{ref}} / 1.7$
- Capacitance slightly higher: $C_{\text{pipe}} = 1.15C_{\text{ref}}$
- $P_{\text{pipe}} = (1.15C_{\text{ref}}) (V_{\text{ref}}/1.7)^2 f_{\text{ref}} \approx 0.39 P_{\text{ref}}$

A Simple Datapath: Summary

Architecture type	Voltage	Area	Power
Simple datapath (no pipelining or parallelism)	5V	1	1
Pipelined datapath	2.9V	1.3	0.39
Parallel datapath	2.9V	3.4	0.36
Pipeline-Parallel	2.0V	3.7	0.2



Multiple Supplies

Multiple Supply Voltages

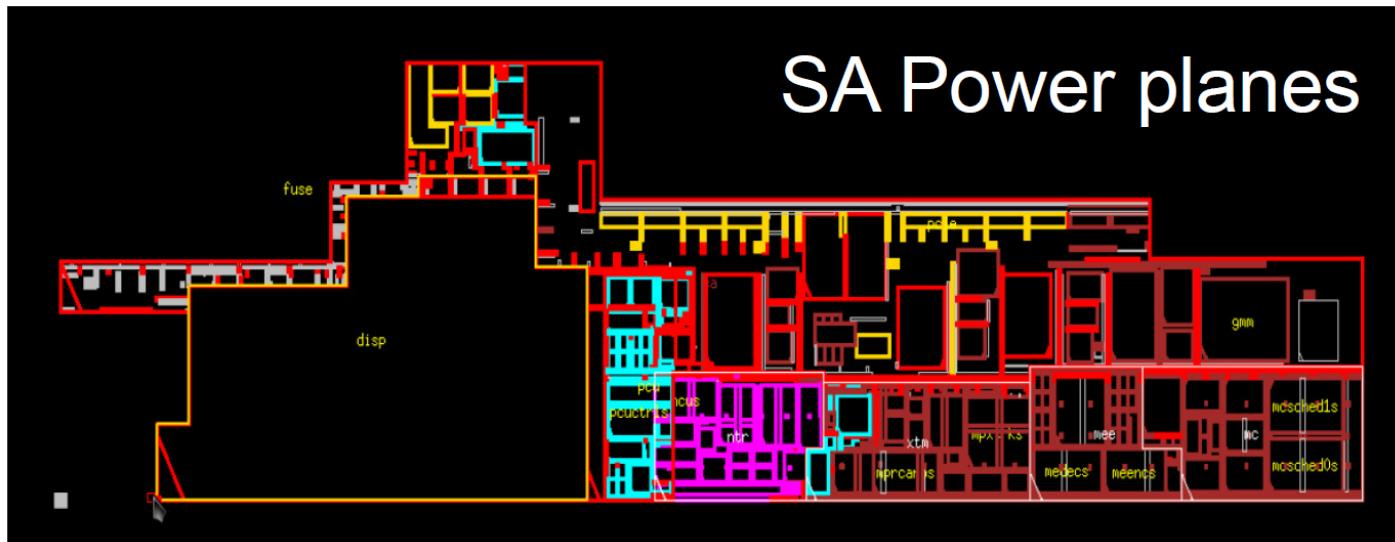
- Block-level supply assignment (“power domains” or “voltage islands”)
 - Higher throughput/lower latency functions are implemented in higher V_{DD}
 - Slower functions are implemented with lower V_{DD}
 - Often called “Voltage islands”
 - Separate supply grids, level conversion performed at block boundaries
- Multiple supplies inside a block
 - Non-critical paths moved to lower supply voltage
 - Level conversion within the block
 - Physical design challenging
 - (Not used in practice)

Power Domains



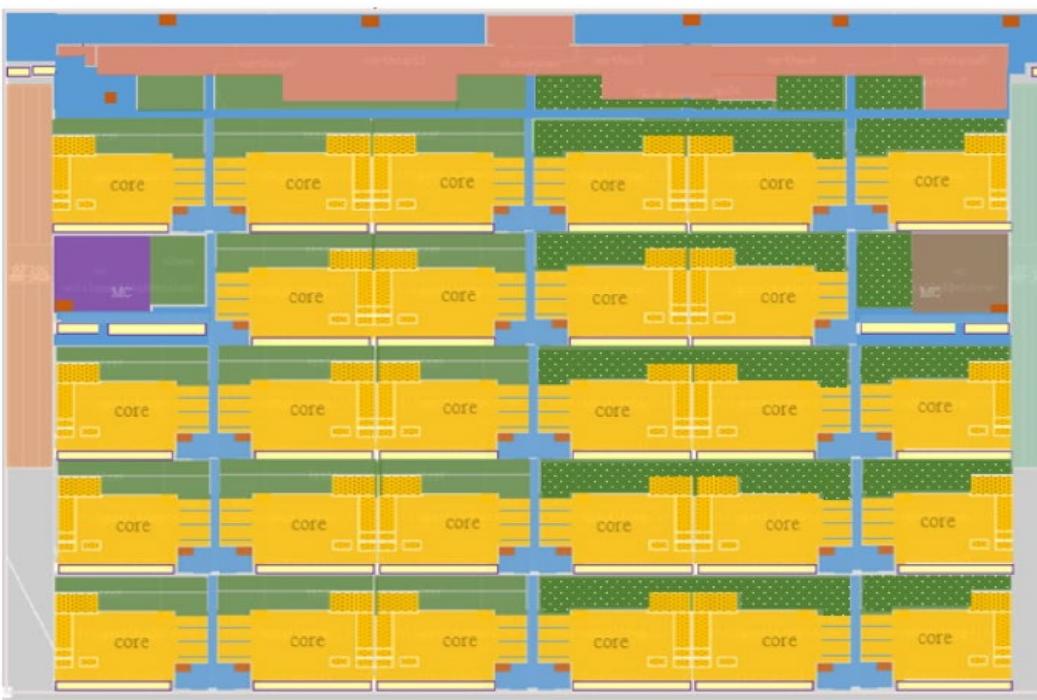
Practical Examples

- Intel Skylake (ISSCC'16)
 - Four power planes indicated by colors



Practical Examples

- Intel 28-core Skylake-SP (ISSCC'18)



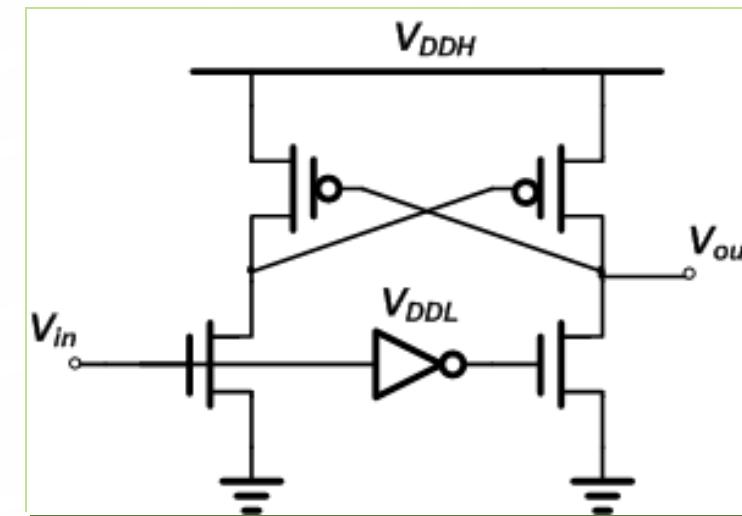
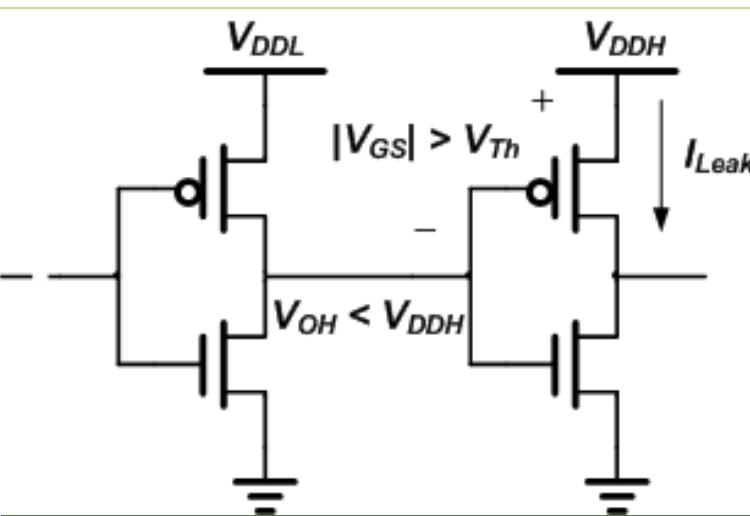
- 9 primary VCC domains are partitioned into 35 VCC planes

- Vcc: core supply (per core)
- } Vccclm: Un-core supply
- Vccsa: System Agent supply
- Vccio: Infrastructure supply
- Vccsfr: PLL supply
- } Vccddrd: DDR logic supply
- } Vccddra: DDR I/O supply

Leakage Issue

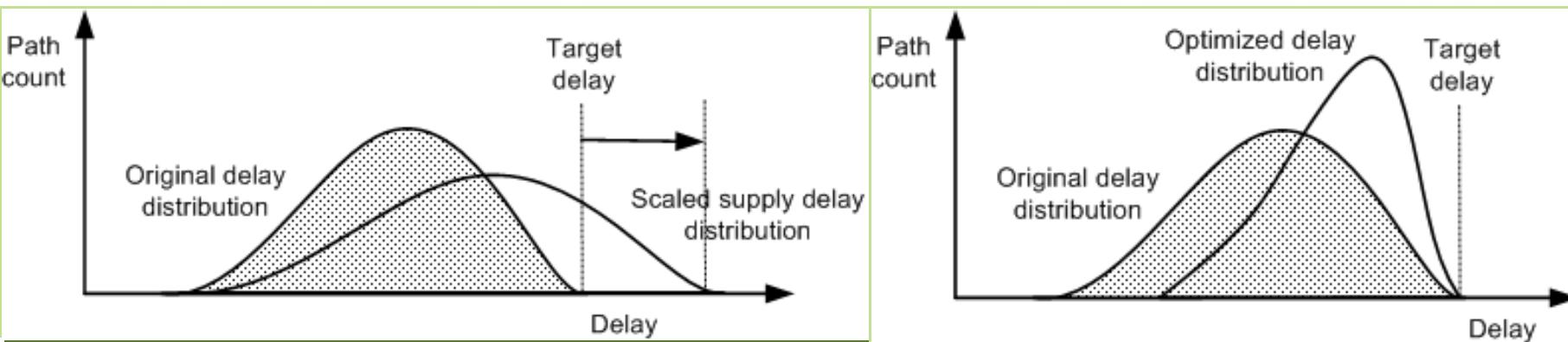
- Driving from V_{DDL} to V_{DDH}

► Level converter



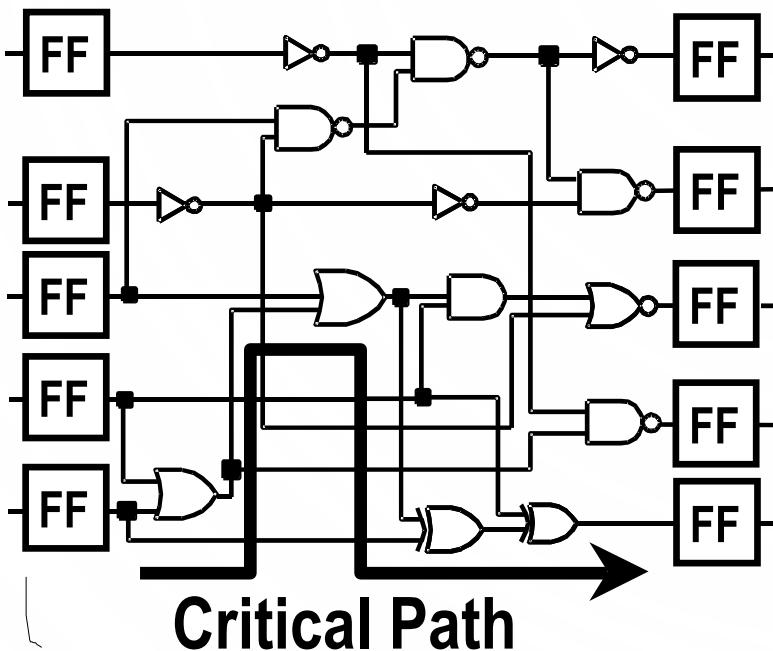
Multiple Supplies Within A Block

- Downsizing, lowering the supply on the critical path will lower the operating frequency
- Downsize (lowering supply) non-critical paths
 - Narrows down the path delay distribution
 - Increases impact of variations

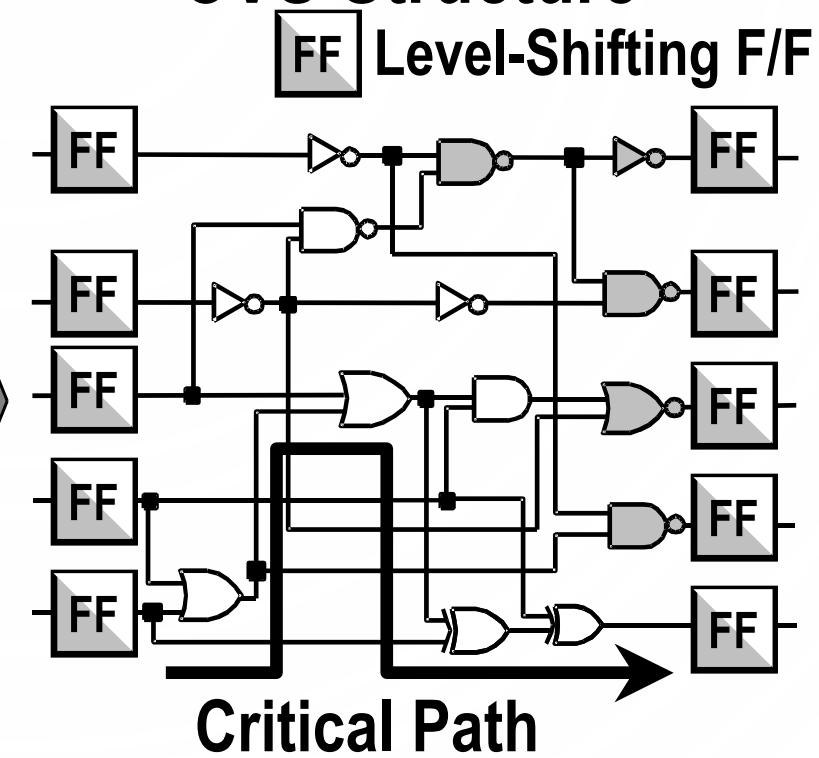


Multiple Supplies in a Block

Conventional Design



CVS Structure



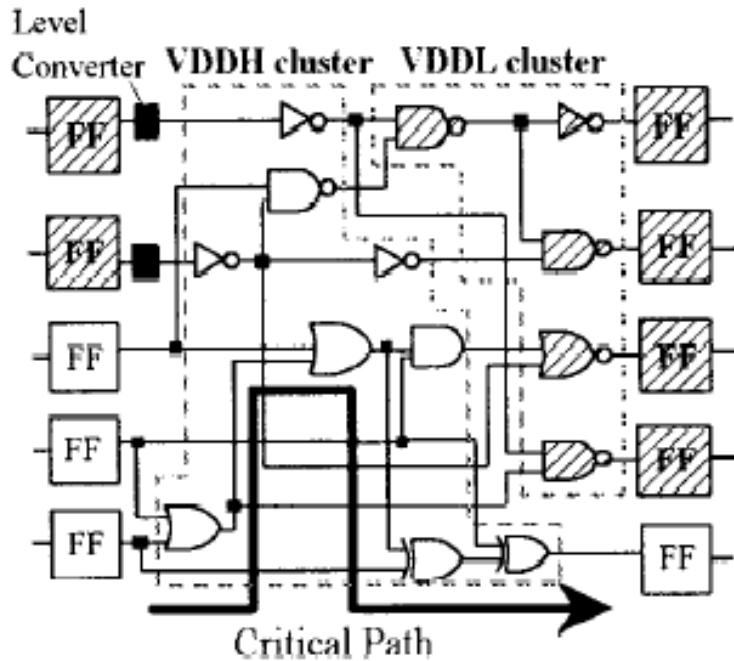
Lower V_{DD} portion is shaded

"Clustered voltage scaling"

M.Takahashi, ISSCC'98.

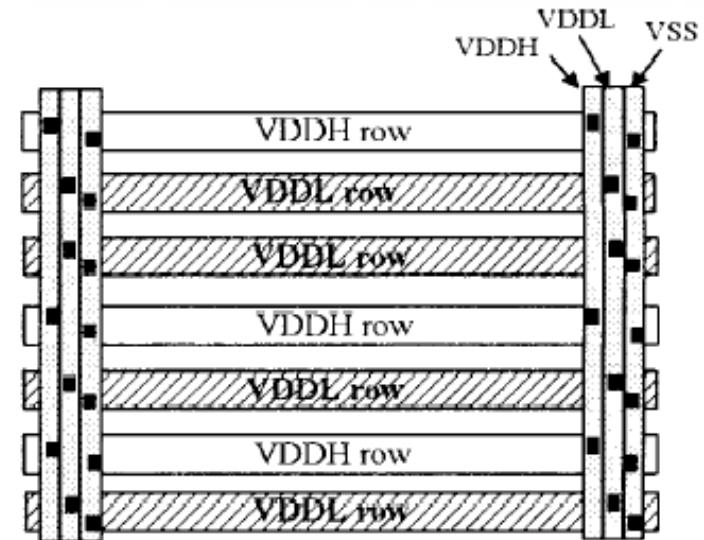
Multiple Supplies in a Block

CVS

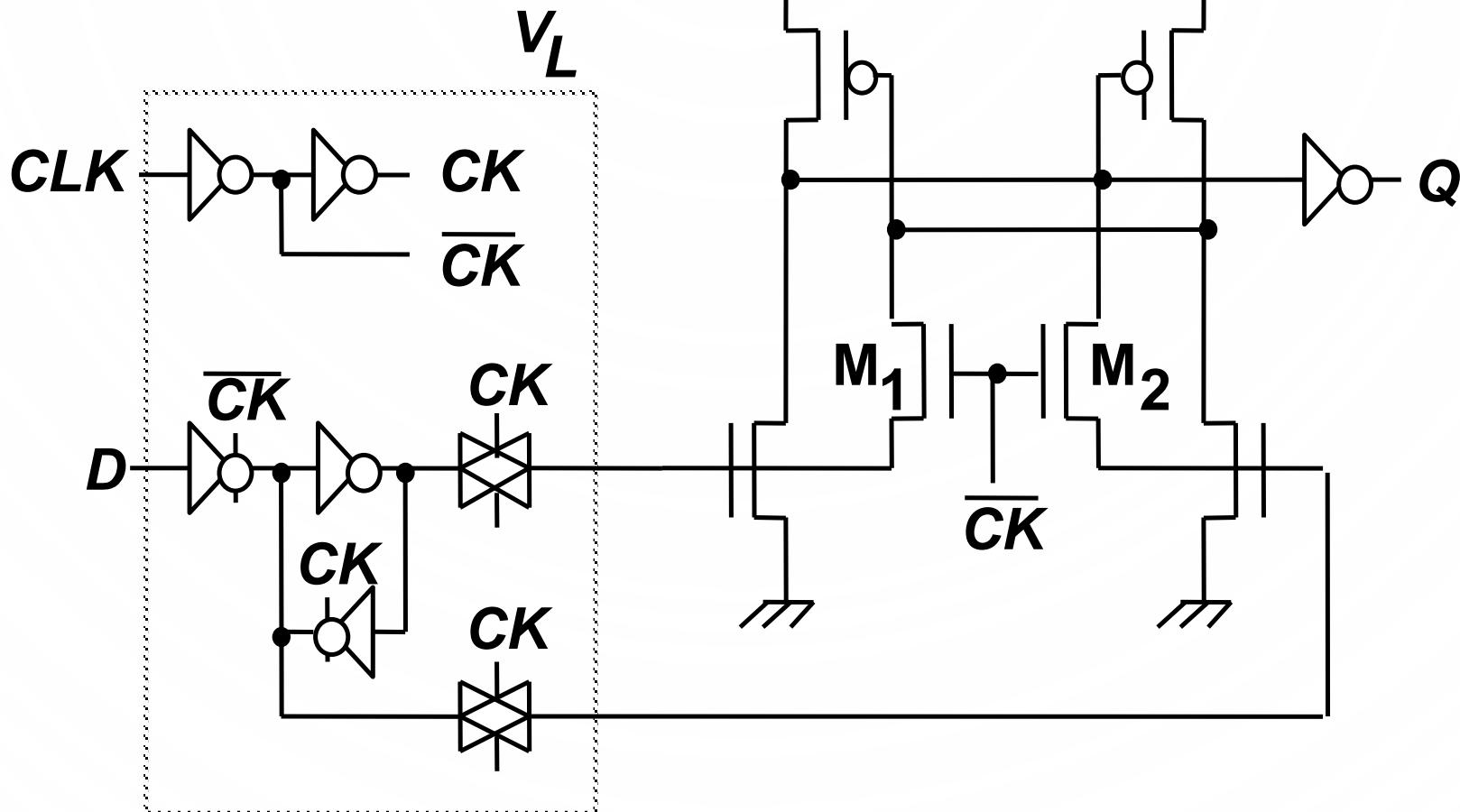


Usami'98

Layout:



Level-Converting Flip-Flop



Summary

- Power-performance tradeoffs
 - Sizing
 - Supplies
 - Thresholds
- Lowering supplies
- Multiple supply voltages

Next Lecture

- Low-power design
 - Dynamic voltage-frequency scaling
 - Clock gating